

Rectifier Diode Avalanche Diode

Replacements see page 3

$$V_{RRM} = 1200-1800 \text{ V}$$

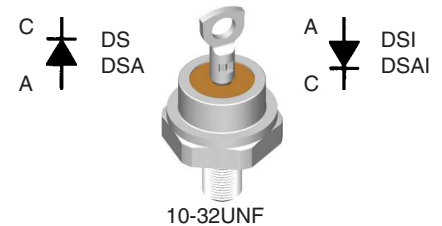
$$I_{F(RMS)} = 40 \text{ A}$$

$$I_{F(AV)M} = 25 \text{ A}$$

V_{RSM} V	$V_{(BR)min}$ ① V	V_{RRM} V	 Anode on stud	 Cathode on stud
1300	-	1200	DS17-12A	DSI17-12A
1300	1300	1200	DSA17-12A	DSAI17-12A
1700	1750	1600	DSA17-16A	DSAI17-16A
1900	1950	1800	DSA17-18A	DSAI17-18A

① Only for Avalanche Diodes

DO-203 AA



A = Anode C = Cathode

Symbol	Test Conditions	Maximum Ratings	
$I_{F(RMS)}$	$T_{VJ} = T_{VJM}$	40	A
$I_{F(AV)M}$	$T_{case} = 125^{\circ}C; 180^{\circ} \text{ sine}$	25	A
P_{RSM}	DSA(I) types, $T_{VJ} = T_{VJM}$, $t_p = 10 \mu s$	7	kW
I_{FSM}	$T_{VJ} = 45^{\circ}C; \quad t = 10 \text{ ms (50 Hz), sine}$	370	A
	$V_R = 0 \quad t = 8.3 \text{ ms (60 Hz), sine}$	400	A
	$T_{VJ} = T_{VJM} \quad t = 10 \text{ ms (50 Hz), sine}$	300	A
	$V_R = 0 \quad t = 8.3 \text{ ms (60 Hz), sine}$	320	A
I^2t	$T_{VJ} = 45^{\circ}C \quad t = 10 \text{ ms (50 Hz), sine}$	680	A ² s
	$V_R = 0 \quad t = 8.3 \text{ ms (60 Hz), sine}$	660	A ² s
	$T_{VJ} = T_{VJM} \quad t = 10 \text{ ms (50 Hz), sine}$	450	A ² s
	$V_R = 0 \quad t = 8.3 \text{ ms (60 Hz), sine}$	430	A ² s
T_{VJ}		-40...+180	$^{\circ}C$
T_{VJM}		180	$^{\circ}C$
T_{stg}		-40...+180	$^{\circ}C$
M_d	Mounting torque	2.2-2.8 19-25	Nm lb.in.
Weight		6	g

Features

- International standard package, JEDEC DO-203 AA (DO-4)
- Planar glassivated chips

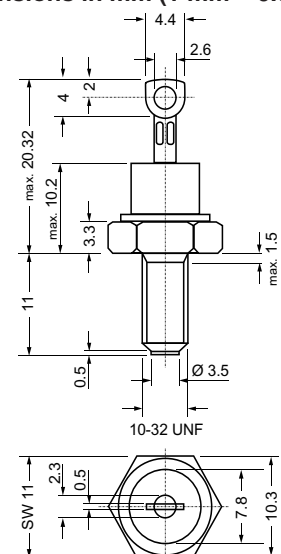
Applications

- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Dimensions in mm (1 mm = 0.0394")



Data according to IEC 60747

IXYS reserves the right to change limits, test conditions and dimensions

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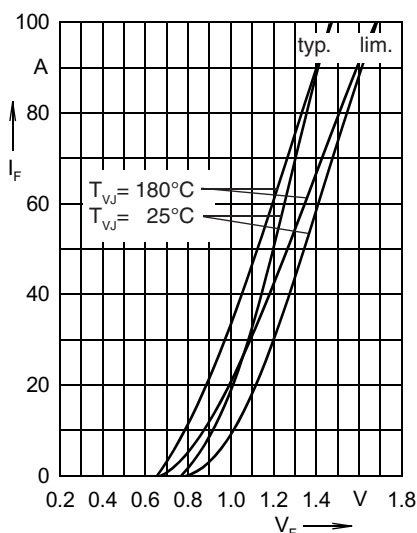


Fig. 1 Forward characteristics

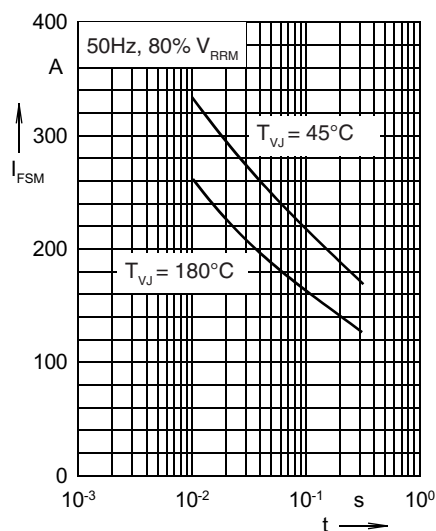


Fig. 2 Surge overload current
 I_{FSM} : crest value, t: duration

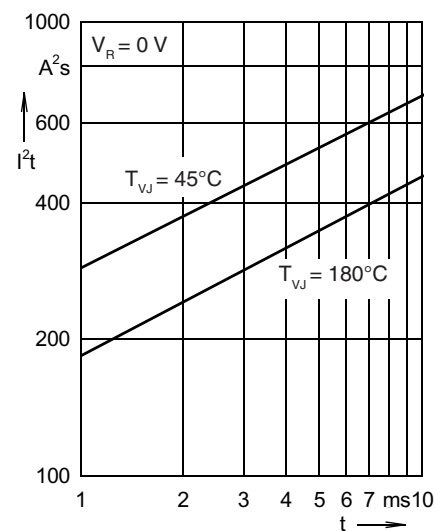


Fig. 3 I^2t versus time (1-10 ms)

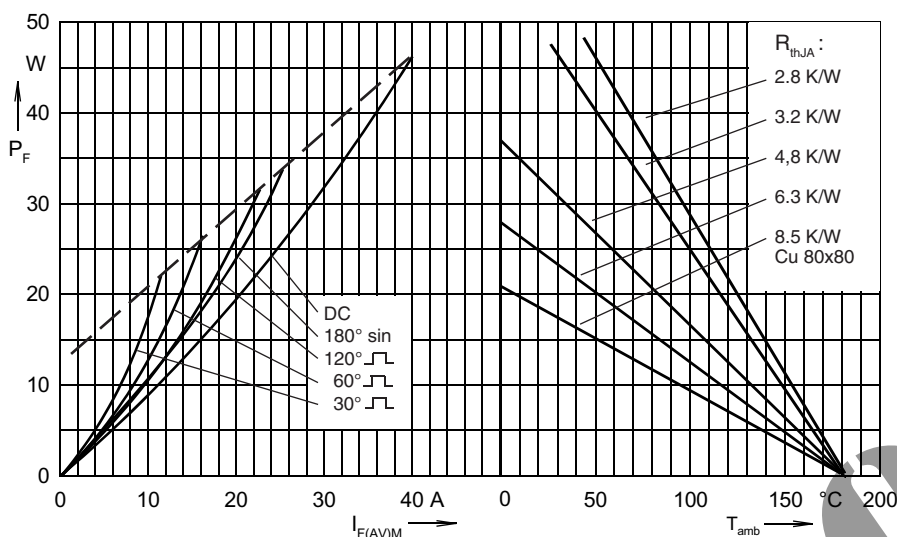


Fig. 4 Power dissipation versus forward current and ambient temperature

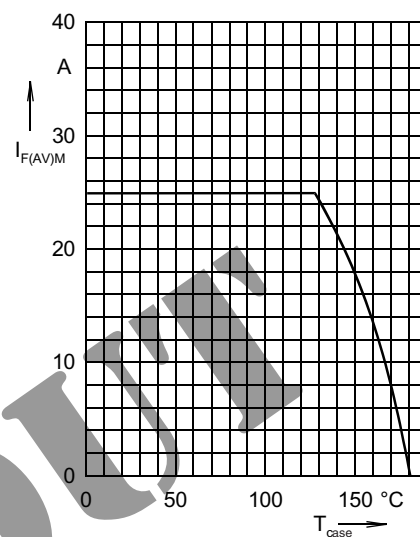


Fig. 5 Max. forward current at case temperature 180° sine

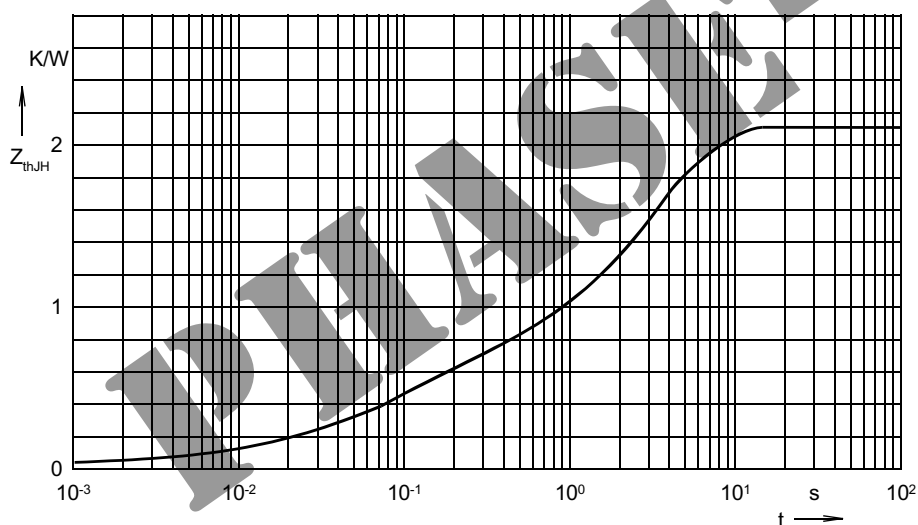


Fig. 6 Transient thermal impedance junction to heatsink

R_{thJH} for various conduction angles d:

d	R_{thJH} (K/W)
DC	2.10
180°	2.23
120°	2.33
60°	2.53
30°	2.72

Constants for Z_{thJH} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.1006	0.0021
2	0.5311	0.0881
3	0.8683	2.968
4	0.600	3.20

Type	Replacements
DSI17-12A	DSI2x55-12A; DMA50I1200HA
DSAI17-12A	DSI2x55-12A; DMA50I1200HA
DSAI17-16A	DSI2x55-12A; DMA50I1200HA
DSAI17-18A	contact factory
DS17-12A	DSI2x55-12A; DMA50I1200HA
DSA17-12A	DSI2x55-12A; DMA50I1200HA
DSA17-16A	DSI2x55-12A; DMA50I1200HA
DSA17-18A	contact factory

PHASE-OUT